

1.5-30MHz 100W Class A/AB **High Performance Amplifier**

- Class A/AB 100W amplifier
- ♦ 1.5-30MHz bandwidth
- 52dB typical gain
- +/- 0.4dB typical gain flatness
- Temperature-compensated bias
- TTL disable
- Available with heatsink and fan



Representative image.

The RFP1.5-30-100 is a Class A/AB amplifier, excellent as a driver stage in military, commercial, industrial, or scientific systems. Its high gain allows it to be driven to full power from signal generator levels. It utilizes a combination of three active device technologies for optimum performance and ruggedness, and is supplied with SMA input and output connectors.

Specifications $V_{sup} = +28VDC$, $I_{DQ} = 0.9A$, $P_{out} = 100W$, $T_{base} = 35^{\circ}C$, $Z_{load} = 50\Omega$					
Parameter	Min	Тур	Max	Units	
Freq. Range	1.5		30	MHz	
P _{1dB}	100	See Figure 4		W	
Input Power		-2	0	dBm	
Gain	50	52		dB	
Gain Flatness		+/-0.4	+/-1.0	dB	
Drain Current		7.2	7.5	Α	
Efficiency	48	50		%	
IRL		-25	-14	dB	
f ₂		-32	-25	dBc	
f ₃		-12	-10	dBc	
IMD ₃ 100W PEP, Δf=10kHz See Fig. 2 for 100kHz		-36	-28	dBc	
Dimensions	2.10 X 5.80 X 1.40 (53.34 X 147.32 X 35.56)			inch (mm)	

Maximum Ratings Operation beyond these ratings will void warranty.				
Parameter	Value			
V_{supply}	24-28VDC			
Bias Current	1.4A			
Drain Current	8.2A			
Load Mismatch*	3:1			
Operating Baseplate Temperature	+5°C to +65°C (Non-condensing)			
Storage Temperature	-40°C to +85°C			

^{*}All phase angles, 100W forward power, current limited to 8.2A for 10 seconds max.

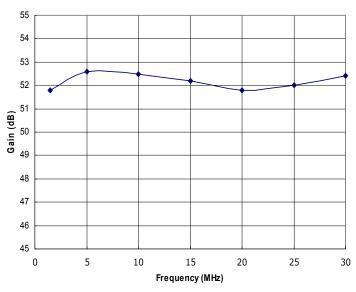
Option Ordering Info			
Heatsink and fan	RFP1.5-30-100-HSF		

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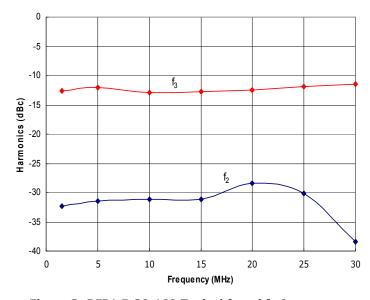
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-20
-25
-25
-30
Δf=100kHz
-45
0 5 10 15 20 25 30
Frequency (MHz)

Figure 1: RFP1.5-30-100 Typical Gain @ Pout = 100W.

Figure 2: RFP1.5-30-100 Typical IMD $_3$ @ 100W PEP, Δf =10kHz and Δf =100kHz. For unbalanced IMD $_3$ U and IMD $_3$ L, only the highest value is shown. For improved linearity, see our RFP1.5-30-35 Class A amp.



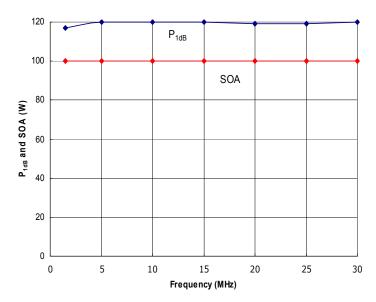


Figure 3: RFP1.5-30-100 Typical f_2 and f_3 @ P_{out} = 100W.

Figure 4: RFP1.5-30-100 Typical P_{1dB} and Safe Operating Area (SOA). Do not exceed the SOA without first contacting RFMPT to discuss your application.

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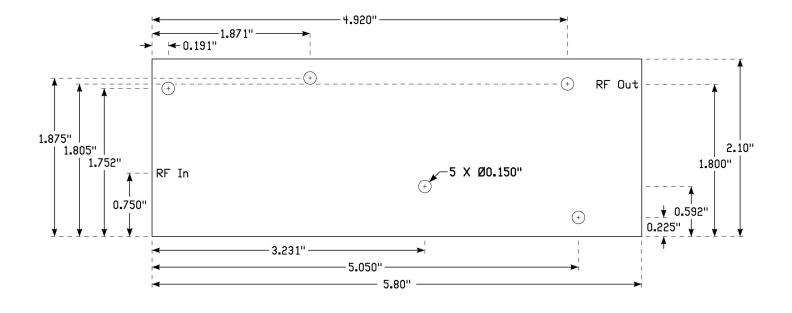
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MADE IN AMERICA



1.5-30MHz 100W Class A/AB High Performance Amplifier

Amplifier Mounting Hole and RF Locations







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Instructions for Amplifier Use

- 1) If not supplied with a heatsink, apply a layer of high quality thermal grease (Wakefield Type 120 or equivalent) to the underside of the amplifier baseplate. Thinner is better, but ensure that when mounted to your heatsink, contact across the *entire* baseplate is made. Gaps and air bubbles will significantly reduce cooling, leading to possible amplifier damage. Use five #6-32 screws to mount the amplifier to your heatsink.
- 2) Guarantee sufficient airflow through the heatsink fins to keep the maximum baseplate temperature directly under the output transistor at or less than that specified in the Maximum Ratings section. Contact RFMPT for details on how to qualify your heatsink's performance, if needed.
- 3) Connect a proper signal source to the RF IN connector, and desired load to the RF OUT connector. Torque connectors to industry standards for the type supplied with the amplifier.
- 4) Connect DC V_{supply} to the terminal provided. Solder a ground wire to the GND pad. Ensure that the connections are of proper polarity, and within the voltage range in the Maximum Ratings section.
- 5) Apply DC power, then sufficient RF drive to achieve desired output level. Ensure that the Safe Operating Area (SOA) power level indicated in Figure 4 is not exceeded, or amplifier damage may occur, and will void the warranty.
- 6) Disable is active high at 5VDC, and disables bias to the driver and output transistors. The MMIC is powered anytime Vcc is applied to the amplifier.
- 7) To disconnect the amplifier, first remove the RF drive, then DC power, then the RF connections.

Contact the factory at sales@rfmpt.com with any questions, or for special options, testing requirements, and/or operating conditions not specified in this document.

Document Control

Revision	Date	Notes		
Α	6-20-2018	Initial release.		

